NLAS4684

Ultra-Low Resistance Dual SPDT Analog Switch

The NLAS4684 is an advanced CMOS analog switch fabricated in Sub−micron silicon gate CMOS technology. The device is a dual Independent Single Pole Double Throw (SPDT) switch featuring Ultra−Low R_{ON} of 0.5 Ω, for the Normally Closed (NC) switch, and 0.8 Ω for the Normally Opened switch (NO) at 2.7 V.

The part also features guaranteed Break Before Make switching, assuring the switches never short the driver.

The NLAS4684 is available in a 2.0 x 1.5 mm bumped die array. The pitch of the solder bumps is 0.5 mm for easy handling.

Features

- Ultra−Low R_{ON}, < 0.5 Ω at 2.7 V
- Threshold Adjusted to Function with 1.8 V Control at V_{CC} = 2.7−3.3 V
- Single Supply Operation from 1.8−5.5 V
- Tiny 2 x 1.5 mm Bumped Die
- Low Crosstalk, < 83 dB at 100 kHz
- Full 0−V_{CC} Signal Handling Capability
- High Isolation, −65 dB at 100 kHz
- Low Standby Current, < 50 nA
- Low Distortion, < 0.14% THD
- R_{ON} Flatness of 0.15 Ω
- Pin for Pin Replacement for MAX4684
- High Continuous Current Capability
  ± 300 mA Through Each Switch
- Large Current Clamping Diodes at Analog Inputs
  ± 300 mA Continuous Current Capability
- Pb−Free Packages are Available

Applications

- Cell Phone
- Speaker Switching
- Power Switching
- Modems
- Automotive

ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS

A1
Microbump−10
CASE 489AA

```
4684
AYWW▪
A1 ○    ▪
```


1
DFN10
CASE 485C

```
1 ○ NLAS
  4684
  ALYW▪
      ▪
```


Micro10
CASE 846B

```
  4684
  AYW▪
1 ○   ▪
```

A	= Assembly Location
L	= Wafer Lot
Y	= Year
WW, W	= Work Week
▪	= Pb−Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

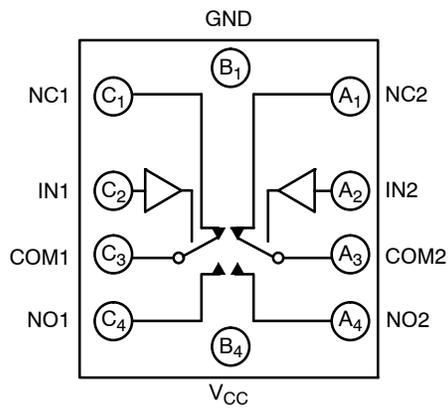| IN 1, 2	NO 1, 2	NC 1, 2
0	OFF	ON
1	ON	OFF

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

NLAS4684
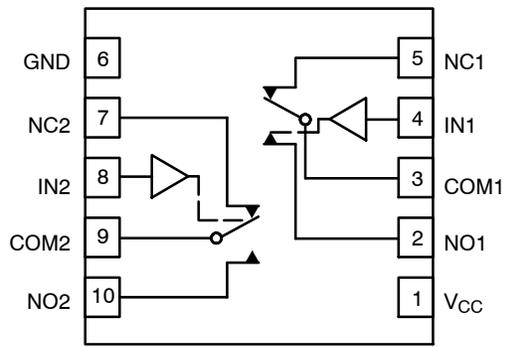
(Top View)

**Figure 1. Pin Connections and Logic Diagram
(DFN10 and Micro10)**

(Top View)

**Figure 2. Pin Connections and Logic Diagram
(Microbump−10)**

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage	-0.5 to $+7.0$	V
V_{IS}	Analog Input Voltage (V_{NO}, V_{NC}, or V_{COM})	$-0.5 \le V_{IS} \le V_{CC} +0.5$	V
V_{IN}	Digital Select Input Voltage	$-0.5 \le V_{I} \le +7.0$	V
I_{anl1}	Continuous DC Current from COM to NC/NO	±300	mA
$I_{anl-pk\ 1}$	Peak Current from COM to NC/NO, 10 duty cycle (Note 1)	±500	mA
I_{clmp}	Continuous DC Current into COM/NO/NC	±300	mA
$I_{clmp\ 1}$	Peak Current into Input Clamp Diodes at COM/NC/NO	±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. Defined as 10% ON, 90% off duty cycle.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage		1.8	5.5	V
V_{IN}	Digital Select Input Voltage		GND	5.5	V
V_{IS}	Analog Input Voltage (NC, NO, COM)		GND	V_{CC}	V
T_A	Operating Temperature Range		-55	$+125$	°C
t_r, t_f	Input Rise or Fall Time, SELECT	$V_{CC} = 3.3\ V \pm 0.3\ V$ $V_{CC} = 5.0\ V \pm 0.5\ V$	0 0	100 20	ns/V
ESD	Human Body Model – All Pins			5	kV

DC CHARACTERISTICS – Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Condition	$V_{CC} \pm 10\%$	Guaranteed Limit			Unit
				$-55°C$ to $25°C$	$<85°C$	$<125°C$	
V_{IH}	Minimum High–Level Input Voltage, Select Inputs (Figure 9)		2.0 2.5 3.0 5.0	1.4 1.4 1.4 2.0	1.4 1.4 1.4 2.0	1.4 1.4 1.4 2.0	V
V_{IL}	Maximum Low–Level Input Voltage, Select Inputs (Figure 9)		2.0 2.5 3.0 5.0	0.5 0.5 0.5 0.8	0.5 0.5 0.5 0.8	0.5 0.5 0.5 0.8	V
I_{IN}	Maximum Input Leakage Current, Select Inputs	$V_{IN} = 5.5\ V$ or GND	5.5	± 1.0	± 1.0	± 1.0	μA
I_{OFF}	Power Off Leakage Current	$V_{IN} = 5.5\ V$ or GND	0	± 10	± 10	± 10	μA
I_{CC}	Maximum Quiescent Supply Current (Note 2)	Select and $V_{IS} = V_{CC}$ or GND	5.5	± 180	± 200	± 200	nA

2. Guaranteed by design.

NLAS4684

DC ELECTRICAL CHARACTERISTICS – Analog Section

Symbol	Parameter	Condition	$V_{CC} \pm 10\%$	Guaranteed Maximum Limit						Unit
				−55°C to 25°C		<85°C		<125°C		
				Min	Max	Min	Max	Min	Max	
R_{ON} (NC)	NC "ON" Resistance (Note 3)	$V_{IN} \leq V_{IL}$ V_{IS} = GND to V_{CC} $I_{IN}I \leq 100$ mA	2.5 3.0 5.0		0.6 0.5 0.4		0.7 0.5 0.4		0.8 0.5 0.5	Ω
R_{ON} (NO)	NO "ON" Resistance (Note 3)	$V_{IN} \geq V_{IH}$ V_{IS} = GND to V_{CC} $I_{IN}I \leq 100$ mA	2.5 3.0 5.0		1.0 0.8 0.8		1.0 0.8 0.8		1.0 1.0 0.9	Ω
R_{FLAT} (NC)	NC_On–Resistance Flatness (Notes 3, 5)	I_{COM} = 100 mA V_{IS} = 0 to V_{CC}	2.5 3.0 5.0		0.15 0.15 0.15		0.15 0.15 0.15		0.15 0.15 0.15	Ω
R_{FLAT} (NO)	NO_On–Resistance Flatness (Notes 3, 5)	I_{COM} = 100 mA V_{IS} = 0 to V_{CC}	2.5 3.0 5.0		0.35 0.35 0.35		0.35 0.35 0.35		0.35 0.35 0.35	Ω
ΔR_{ON}	On–Resistance Match Between Channels (Notes 3 and 4)	V_{IS} = 1.3 V; I_{COM} = 100 mA V_{IS} = 1.5 V; I_{COM} = 100 mA V_{IS} = 2.8 V; I_{COM} = 100 mA	2.5 3.0 5.0		0.18 0.06 0.06		0.18 0.06 0.06		0.18 0.06 0.06	Ω
$I_{NC(OFF)}$ $I_{NO(OFF)}$	NC or NO Off Leakage Current (Figure 13) (Note 3)	$V_{IN} = V_{IL}$ or V_{IH} V_{NO} or V_{NC} = 1.0 V_{COM} = 4.5 V	5.5	−1	1	−10	10	−100	100	nA
$I_{COM(ON)}$	COM ON Leakage Current (Figure 13) (Note 3)	$V_{IN} = V_{IL}$ or V_{IH} V_{NO} 1.0 V or 4.5 V with V_{NC} floating or V_{NC} 1.0 V or 4.5 V with V_{NO} floating V_{COM} = 1.0 V or 4.5 V	5.5	−2	2	−20	20	−200	200	nA

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
4. $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ between NC1 and NC2 or between NO1 and NO2.
5. Flatness is defined as the difference between the maximum and minimum value of on–resistance as measured over the specified analog signal ranges.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns) (Typical characteristics are at 25°C)

Symbol	Parameter	Test Conditions	V_{CC} (V)	V_{IS} (V)	Guaranteed Maximum Limit							Unit
					−55°C to 25°C			<85°C		<125°C		
					Min	Typ	Max	Min	Max	Min	Max	
t_{ON}	Turn−On Time	$R_L = 50\ \Omega$, $C_L = 35$ pF (Figures 4 and 5)	2.5	1.3			60		70		70	ns
			3.0	1.5			50		60		60	
			5.0	2.8			30		35		35	
t_{OFF}	Turn−Off Time	$R_L = 50\ \Omega$, $C_L = 35$ pF (Figures 4 and 5)	2.5	1.3			50		55		55	ns
			3.0	1.5			40		50		50	
			5.0	2.8			30		35		35	
t_{BBM}	Minimum Break−Before−Make Time (Note 6)	$V_{IS} = 3.0$ $R_L = 300\ \Omega$, $C_L = 35$ pF (Figure 3)	3.0	1.5	2	15						ns

		Typical @ 25, $V_{CC} = 5.0$ V	
C_{NC} Off	NC Off Capacitance, f = 1 MHz	102	pF
C_{NO} Off	NO Off Capacitance, f = 1 MHz	104	
C_{NC} On	NC On Capacitance, f = 1 MHz	322	
C_{NO} On	NO On Capacitance, f = 1 MHz	330	

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

Symbol	Parameter	Condition		V_{CC} V	Typical 25°C	Unit
BW	Maximum On−Channel −3dB Bandwidth or Minimum Frequency Response	$V_{IN} = 0$ dBm V_{IN} centered between V_{CC} and GND (Figure 6)	NC	3.0	6.5	MHz
			NO	3.0	9.5	
V_{ONL}	Maximum Feed−through On Loss	$V_{IN} = 0$ dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 6)		3.0	−0.05	dB
V_{ISO}	Off−Channel Isolation (Note 7)	f = 100 kHz; $V_{IS} = 1$ V RMS; $C_L = 5$ nF V_{IN} centered between V_{CC} and GND(Figure 6)		3.0	−65	dB
Q	Charge Injection Select Input to Common I/O (Figures 10 and 11)	$V_{IN} = V_{CC\ to}$ GND, $R_{IS} = 0\ \Omega$, $C_L = 1$ nF $Q = C_L − \Delta V_{OUT}$ (Figure 7)		3.0	15	pC
THD	Total Harmonic Distortion THD + Noise (Figure 9)	$F_{IS} = 20$ Hz to 100 kHz, $R_L = R_{gen} = 600\ \Omega$, $C_L = 50$ pF $V_{IS} = 1$ V RMS		3.0	0.14	%
VCT	Channel−to−Channel Crosstalk	f = 100 kHz; $V_{IS} = 1$ V RMS, $C_L = 5$ pF, $R_L = 50\ \Omega$ V_{IN} centered between V_{CC} and GND (Figure 6)		3.0	−83	dB

6. −55°C specifications are guaranteed by design.
7. Off−Channel Isolation = 20log10 (Vcom/Vno) (See Figure 6).
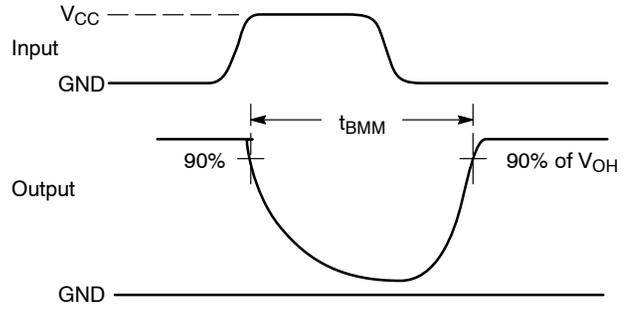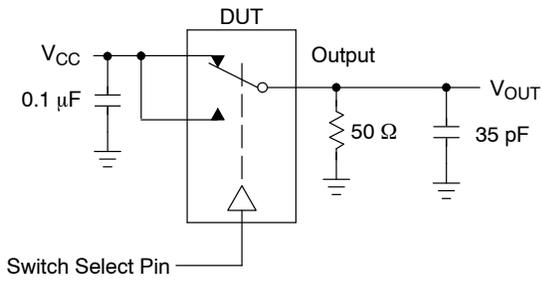
Figure 3. t$_{BBM}$ (Time Break−Before−Make)
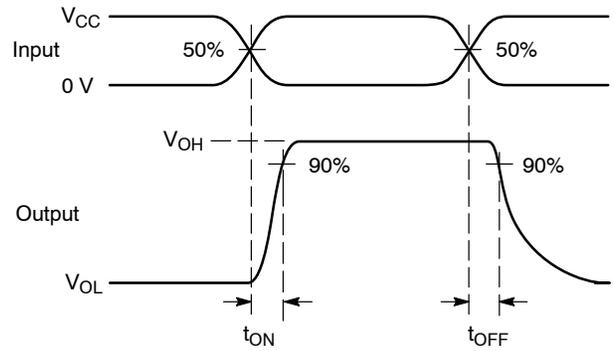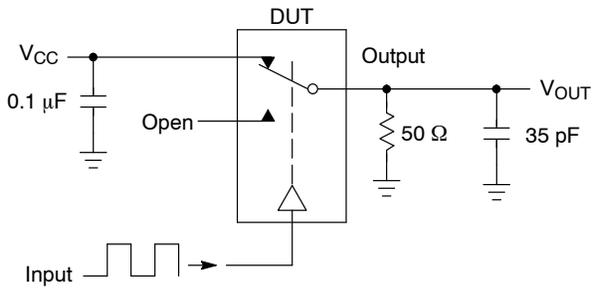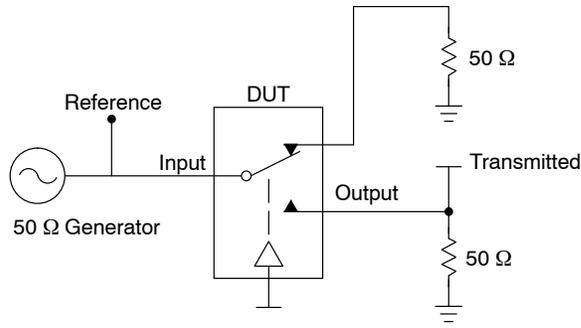

Figure 4. t$_{ON}$/t$_{OFF}$
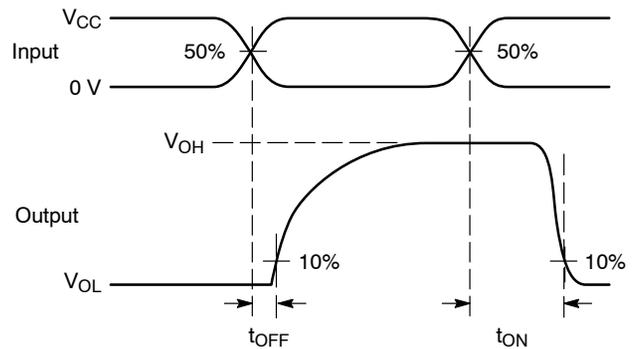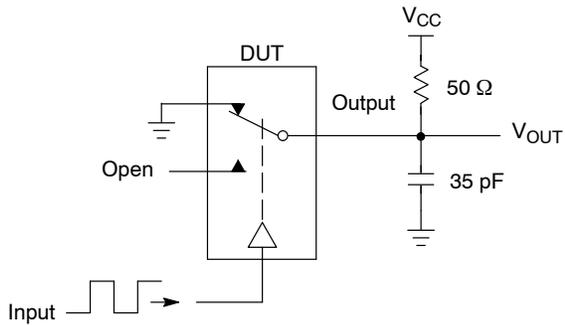
Figure 5. t$_{ON}$/t$_{OFF}$

Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO}, Bandwidth and V_{ONL} are independent of the input signal direction.

V_{ISO} = Off Channel Isolation = $20 \, Log \left(\dfrac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz

V_{ONL} = On Channel Loss = $20 \, Log \left(\dfrac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz to 50 MHz

Bandwidth (BW) = the frequency 3 dB below V_{ONL}
V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω

Figure 6. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}
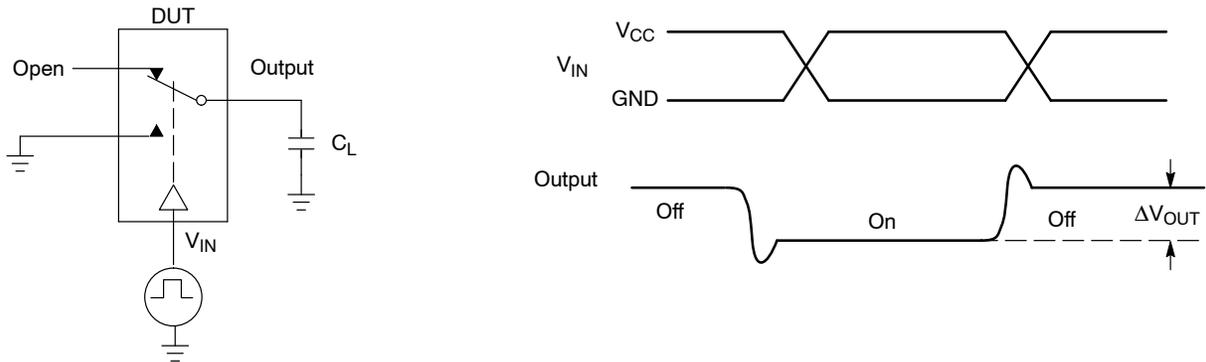
Figure 7. Charge Injection: (Q)
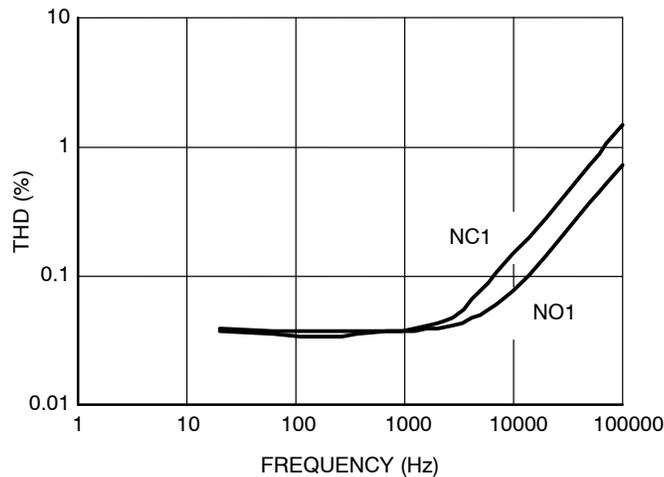
Figure 8. Total Harmonic Distortion Plus Noise Versus Frequency

NLAS4684
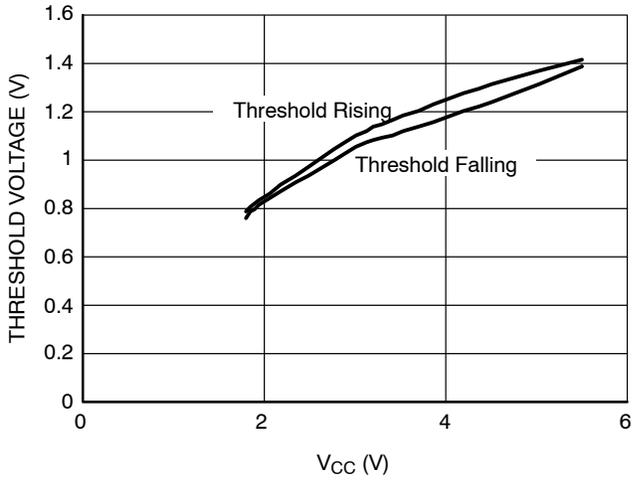
Figure 9. Voltage in Threshold on Logic Pins
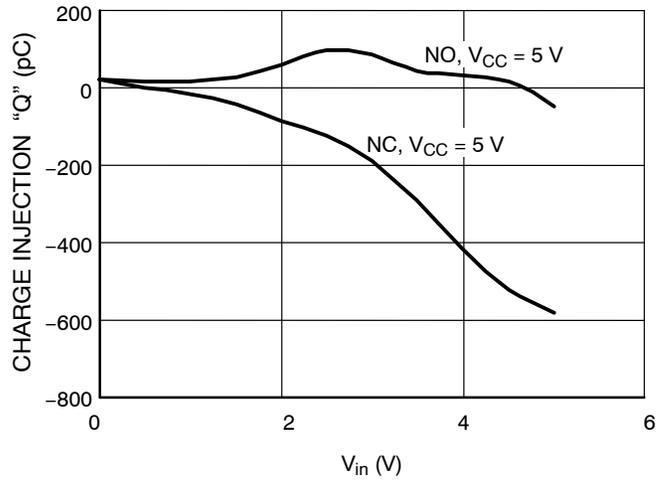
Figure 10. Charge Injection versus V_{is}
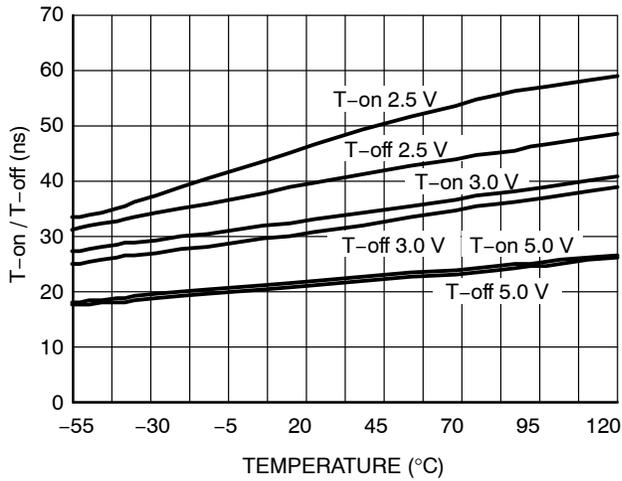
Figure 11. T−on / T−off Time versus Temperature
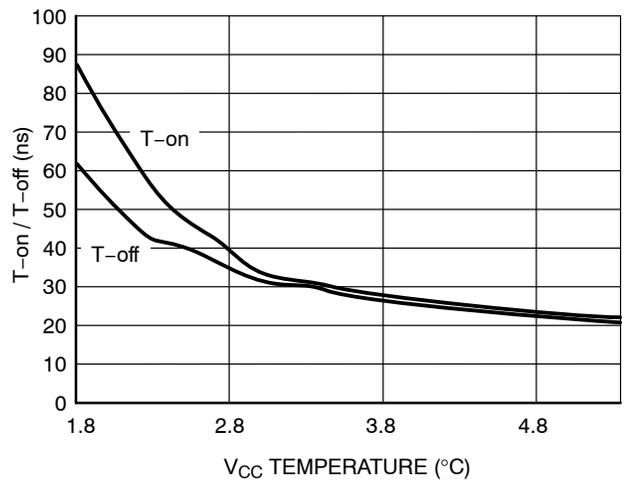
Figure 12. T−on / T−off Time versus Temperature
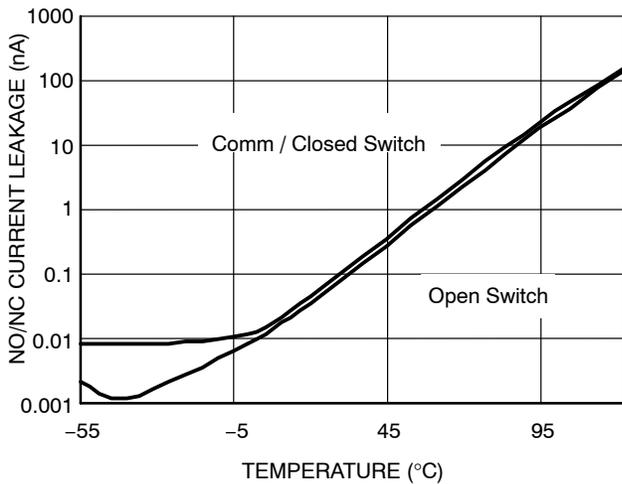
Figure 13. NO/NC Current Leakage Off and On, V_{CC} = 5 V
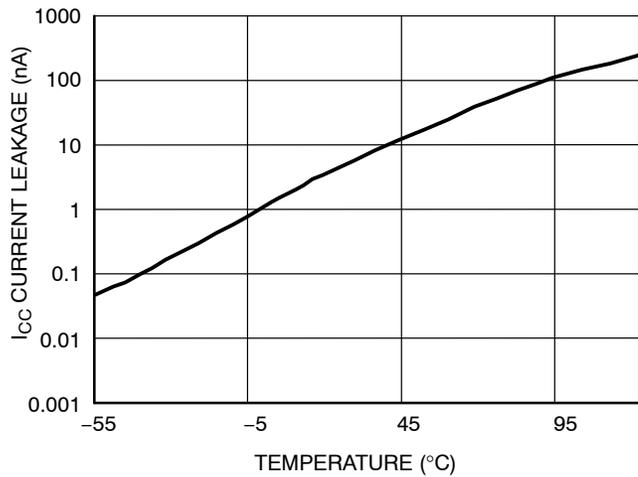
Figure 14. I_{CC} Current Leakage versus Temperature V_{CC} = 5.5 V
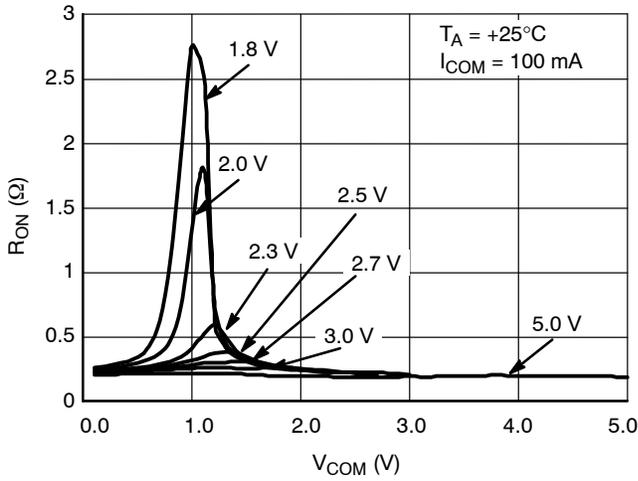
**Figure 15. NC On−Resistance versus
COM Voltage**
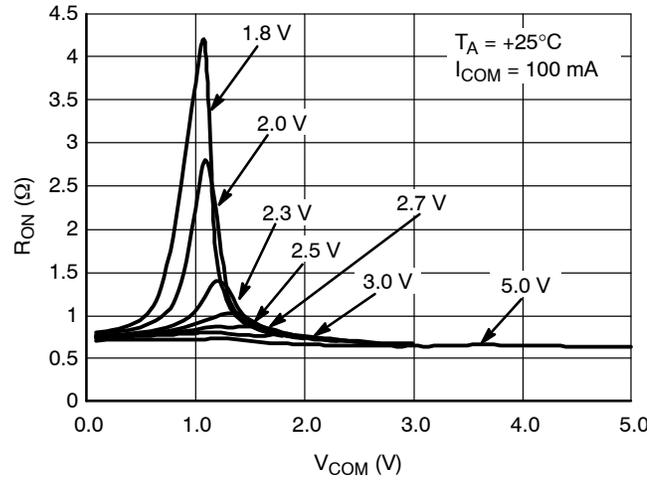
**Figure 16. NO On−Resistance versus
COM Voltage**
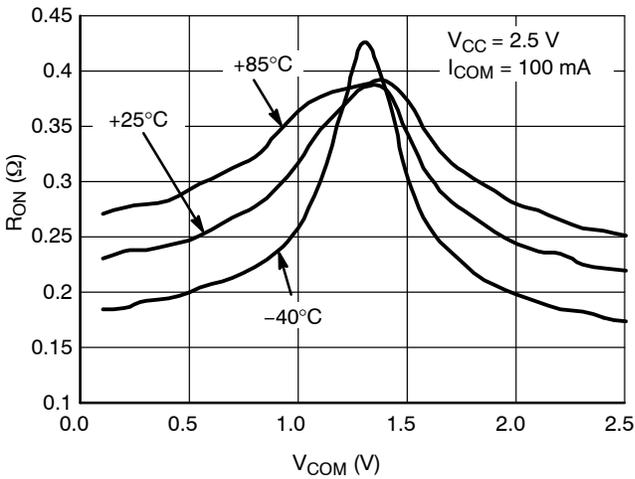
**Figure 17. NC On−Resistance versus
COM Voltage**
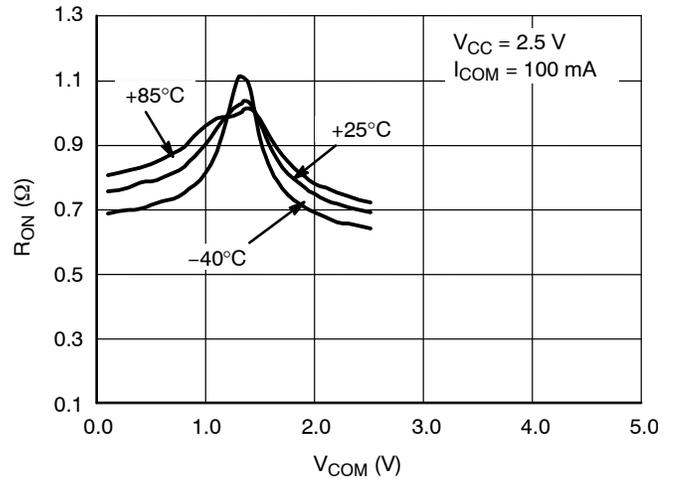
**Figure 18. NO On−Resistance versus
COM Voltage**
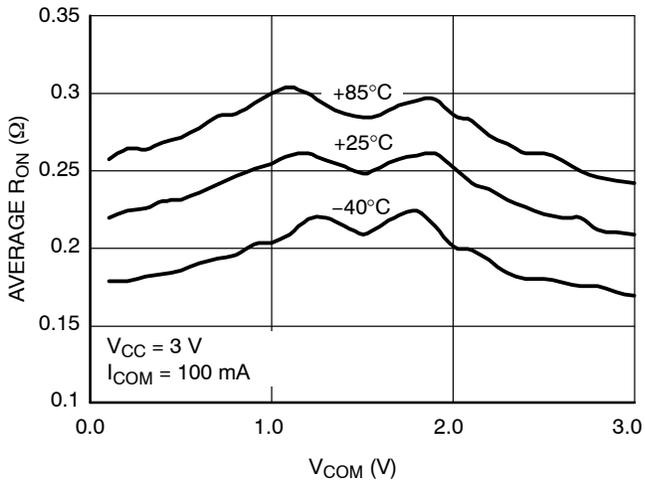
**Figure 19. NC On−Resistance versus
COM Voltage**
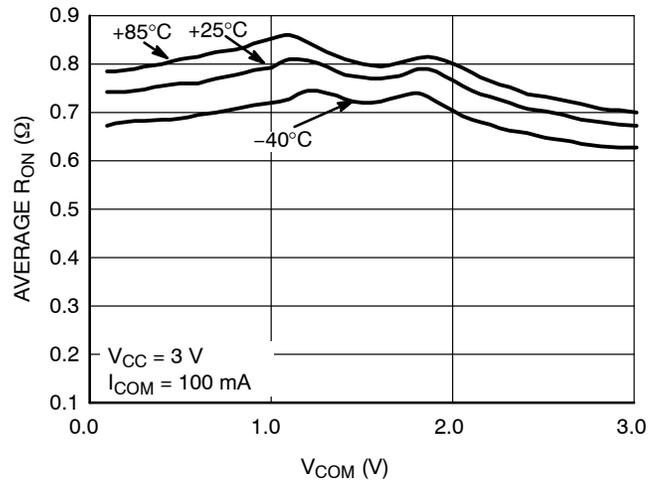
**Figure 20. NC On−Resistance versus
COM Voltage**
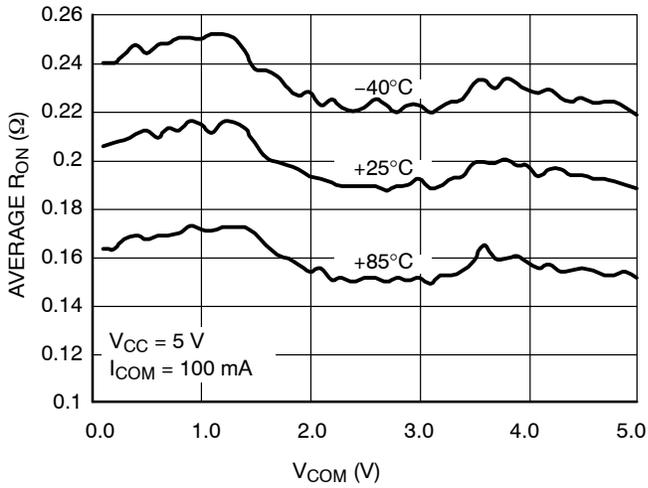
Figure 21. NC On−Resistance versus
COM Voltage
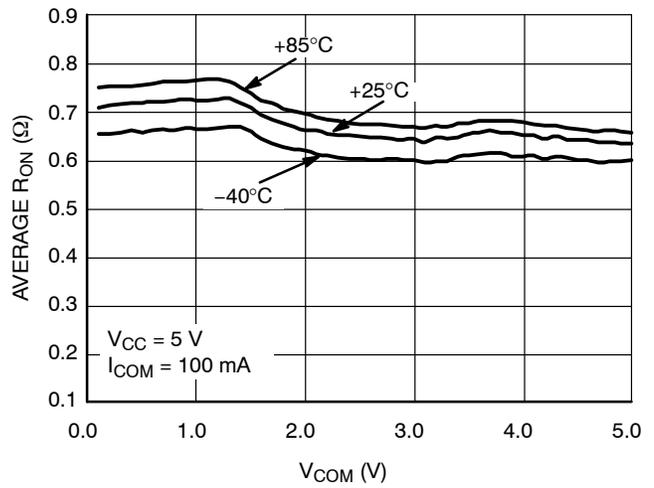
Figure 22. NO On−Resistance versus
COM Voltage
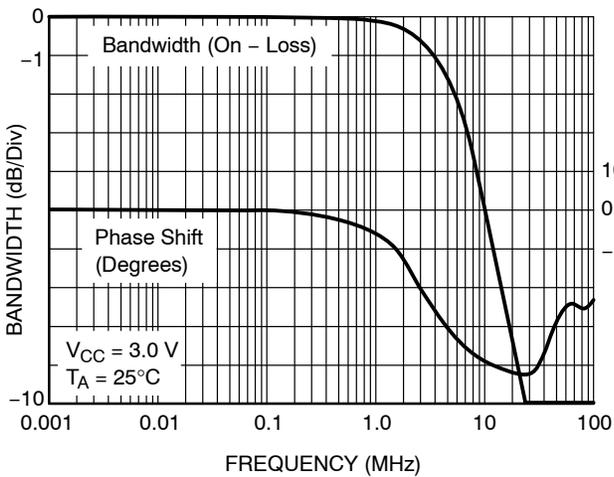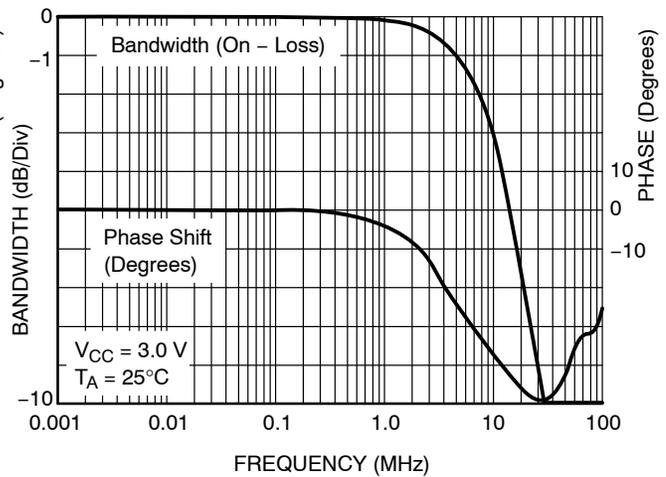

Figure 23. NC Bandwidth and Phase Shift
versus Frequency

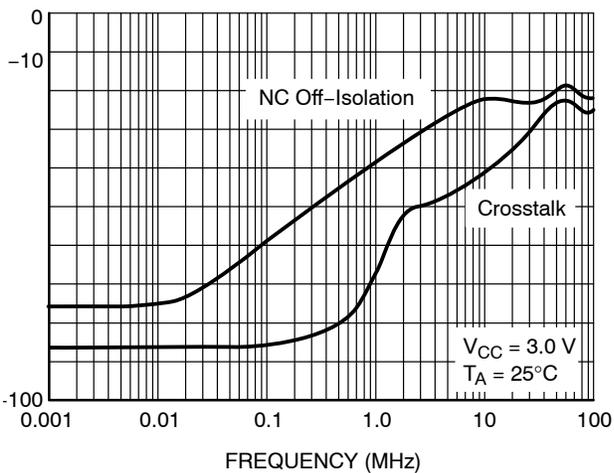Figure 24. NO Bandwidth and Phase Shift
versus Frequency
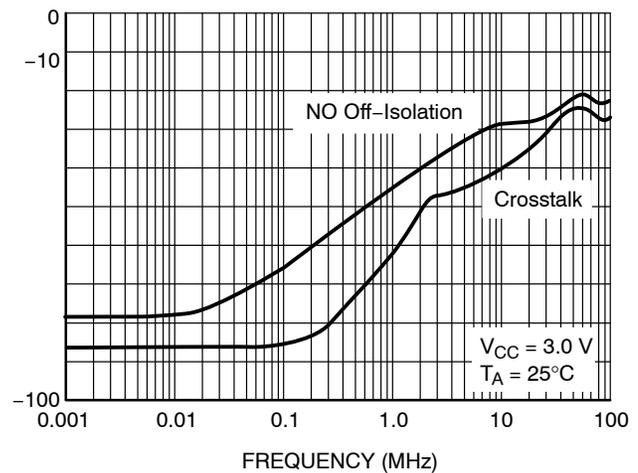

Figure 25. NC Off Isolation and Crosstalk

Figure 26. NO Off Isolation and Crosstalk

NLAS4684

ORDERING INFORMATION

Device	Package	Shipping†
NLAS4684FCT1	Microbump−10	3000 / Tape & Reel
NLAS4684FCT1G	Microbump−10 (Pb−Free)	3000 / Tape & Reel
NLAS4684FCTCG	Microbump−10 (Pb−Free)	3000 / Tape & Reel
NLAS4684MNR2	DFN10	3000 / Tape & Reel
NLAS4684MNR2G	DFN10 (Pb−Free)	3000 / Tape & Reel
NLAS4684MR2	Micro10	4000 / Tape & Reel
NLAS4684MR2G	Micro10 (Pb−Free)	4000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NLAS4684

PACKAGE DIMENSIONS
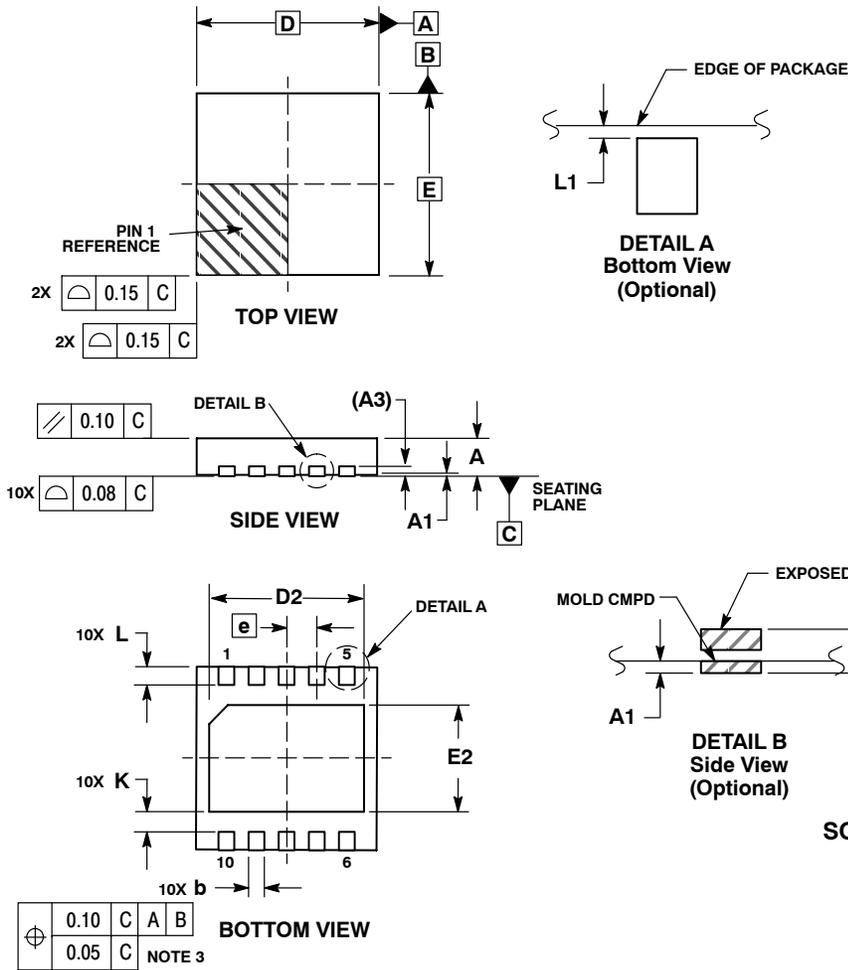
Microbump−10
CASE 489AA−01
ISSUE A
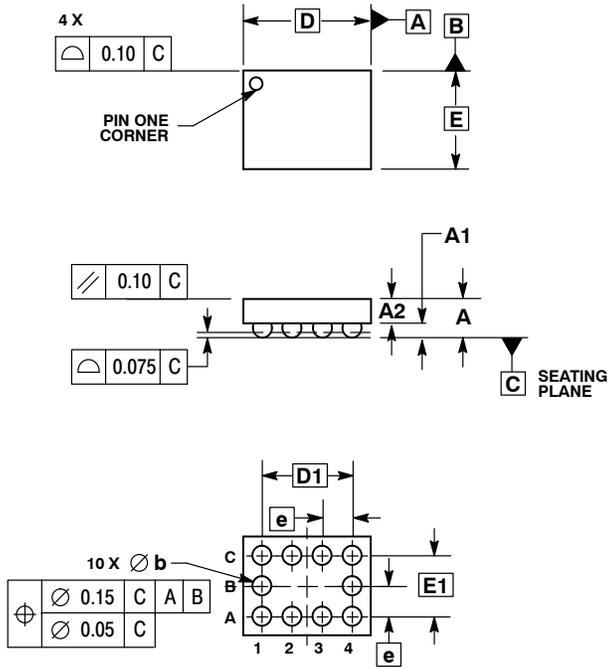
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

DIM	MILLIMETERS	
	MIN	MAX
A	−−−	0.650
A1	0.210	0.270
A2	0.280	0.380
D	1.965 BSC	
E	1.465 BSC	
b	0.250	0.350
e	0.500 BSC	
D1	1.500 BSC	
E1	1.000 BSC	

NLAS4684

PACKAGE DIMENSIONS

DFN10, 3 x 3mm, 0.5mm Pitch
CASE 485C–01
ISSUE A

TOP VIEW

PIN 1
REFERENCE

D A B

E

2X △ 0.15 C

2X △ 0.15 C

SIDE VIEW

DETAIL B

(A3)

A

A1

// 0.10 C

10X △ 0.08 C

SEATING PLANE

C

BOTTOM VIEW

D2

10X L

10X K

1

5

10

6

10X b

e

E2

⊕ 0.10 C A B
0.05 C NOTE 3

DETAIL A
Bottom View
(Optional)

EDGE OF PACKAGE

L1

DETAIL B
Side View
(Optional)

MOLD CMPD

EXPOSED Cu

A3

A1

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. TERMINAL b MAY HAVE MOLD COMPOUND MATERIAL ALONG SIDE EDGE. MOLD FLASHING MAY NOT EXCEED 30 MICRONS ONTO BOTTOM SURFACE OF TERMINAL b.
6. DETAILS A AND B SHOW OPTIONAL VIEWS FOR END OF TERMINAL LEAD AT EDGE OF PACKAGE.

| DIM | MILLIMETERS | |
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20 REF	
b	0.18	0.30
D	3.00 BSC	
D2	2.45	2.55
E	3.00 BSC	
E2	1.75	1.85
e	0.50 BSC	
K	0.19 TYP	
L	0.35	0.45
L1	0.00	0.03

SOLDERING FOOTPRINT*

2.6016

2.1746

1.8508

3.3048
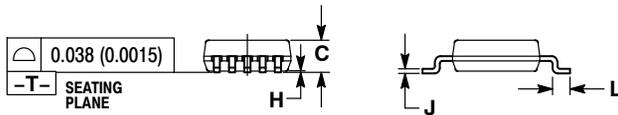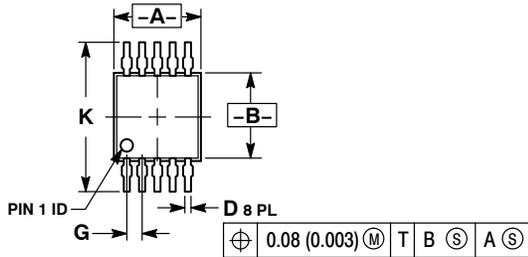
10X
0.5651

10X
0.3008

0.5000 PITCH
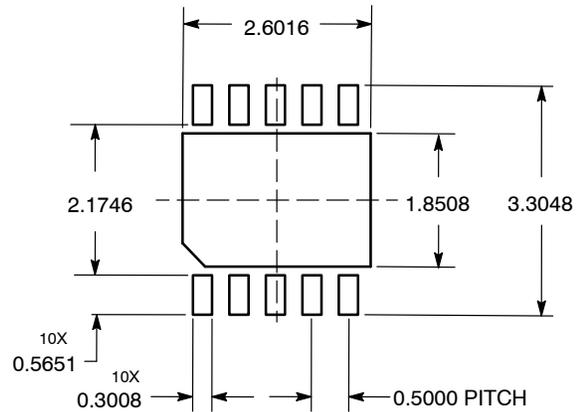
DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NLAS4684

PACKAGE DIMENSIONS

Micro10
CASE 846B–03
ISSUE D

PIN 1 ID

K

G

D 8 PL

$\oplus$ | 0.08 (0.003) Ⓜ | T | B Ⓢ | A Ⓢ

$\bigcirc$ 0.038 (0.0015)
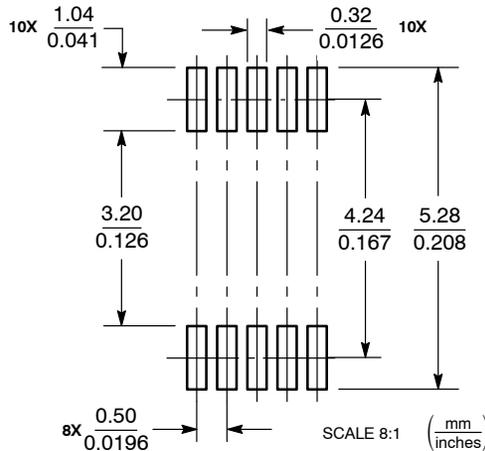
–T– SEATING PLANE

C

H

J

L

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION "B" DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846B–01 OBSOLETE. NEW STANDARD 846B–02

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.95	1.10	0.037	0.043
D	0.20	0.30	0.008	0.012
G	0.50 BSC		0.020 BSC	
H	0.05	0.15	0.002	0.006
J	0.10	0.21	0.004	0.008
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

SOLDERING FOOTPRINT*

10X $\dfrac{1.04}{0.041}$

$\dfrac{0.32}{0.0126}$ 10X

$\dfrac{3.20}{0.126}$

$\dfrac{4.24}{0.167}$ $\dfrac{5.28}{0.208}$

8X $\dfrac{0.50}{0.0196}$

SCALE 8:1 $\left(\dfrac{mm}{inches}\right)$

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